DOCKET NO.: 3442

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Tomohiro Kawase et al.

Art Unit:

SERIAL NO.: 08/843,124

Examiner:

FILED: April 25, 1997

FOR: METHOD OF PREPARING GROUP III-V

COMPOUND SEMICONDUCTOR CRYSTAL

ASSISTANT COMMISSIONER FOR PATENTS

WASHINGTON, D. C. 20231



TRANSMITTED HEREWITH IS A RESPONSE TO THE OFFICE ACTION OF JANUARY 12, 1998 IN THE ABOVE IDENTIFIED PATENT APPLICATION COMPRISING 22 PAGES. ALSO ENCLOSED ARE THE FOLLOWING: PRIORITY DOCUMENT NO. 8-107009; A COPY OF THE OFFICIAL FILING RECEIPT AND A COPY OF OUR RETURN RECEIPT POSTCARD OF 4/25/97; A COPY OF THE ORIGINALLY FILED DRAWINGS; A CERTIFIED TRANSLATION OF JAPANESE PATENT APPLICATION NO. 8-107009 AND A TRANSLATOR'S DECLARATION; ENGLISH TEXT OF THE KAWASE ET AL. ARTICLE; REFERENCE MAT. RELATING TO THE 1996 IEEE SEMICONDUCTING AND SEMI-INSULATING MATERIALS CONFERENCE IEEE SIMC-9.

AN ADDITIONAL FEE IS REQUIRED, AS SHOWN BELOW.

CLAIMS RE- MAINING AFTER AMENDMENT	HIGHEST NO. PREVIOUSLY PAID FOR	PRESENT EXTRA	SMALL ENTITY	OR	LARGE ENTITY	ADDITIONAL FEE
TOTAL:23	MINUS:20	= 3	x =\$		X=\$22.00	=\$ 66.00
INDEP: 3	MINUS: 3	= 0	X =\$		X=\$ 0	=\$ O
					TOTAL ADDITION. FEE DUE:	=\$ 66.00

PLEASE CHARGE THE EXTRA CLAIM FEE IN THE AMOUNT OF \$66.00 TO MY DEPOSIT ACCOUNT 50-0507.

50-0507

Fasse 2 April 13,

CERTIFICATE OF MAILING

I certify that this RESPONSE...WITH ENCLOSURES, is being mailed on: April 13, 1998, as first-class mail, with sufficient postage prepaid, in an envelope addressed to: ASSISTANT COMMISSIONER FOR

PATENTS Washington D. C. 20231. 4//3/98 Walter F. Fasse - April 13, 1998

3442/WFF:ar

PTO-103X (Rev. 3-95)

FILING RECEIPT
CORRECTED



UNITED STATES PARTMENT OF COMMERCE Patent and Trademark Office ASSISTANT SECRETARY AND COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231

04/16/98

SAPPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
08/843,124	04/25/97	1763	\$770.00	3442	7	20	1

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Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Application Processing Division's Customer Correction Branch within 10 days of receipt. Please provide a copy of the Filing Receipt with the changes noted thereon.

Applicant(s)

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FOREIGN APPLICATIONS-

JAPAN

8-107009

04/29/96

TITLE
METHOD OF PREPARING GROUP III-V COMPOUND SEMICONDUCTOR CRYSTAL

PRELIMINARY CLASS: 117

